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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
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Cem Basceri

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EXAMINER

ARENA, ANDREW OWENS

ART UNIT

PAPER NUMBER

2811

DATE MAILED: 06/29/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary	Application No. 10/669,384	Applicant(s) BASCERI ET AL.	
	Examiner Andrew O. Arena	Art Unit 2811	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 17 April 2006.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 67-114 is/are pending in the application.
- 4a) Of the above claim(s) 96-114 is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 67-69, 71-74, 78, 80, 83-86 and 88-90 is/are rejected.
- 7) ☐ Claim(s) 70, 75-77, 79, 81, 82, 87, and 91-95 is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☒ The specification is objected to by the Examiner.
- 10) ☒ The drawing(s) filed on 24 September 2003 is/are: a) ☒ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
 2. ☐ Certified copies of the priority documents have been received in Application No. _____.
 3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|---|---|
| 1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413)
Paper No(s)/Mail Date. _____ |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | 5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152) |
| 3) <input checked="" type="checkbox"/> Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)
Paper No(s)/Mail Date <u>12/29/2003</u> | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

Specification

The title of the invention is not descriptive. A new title is required that is clearly indicative of the invention to which the claims are directed.

The following title is suggested: Method for forming electrodes wherein substrate oxygen diffuses through one metal layer and oxidizes a second.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 67-69, 71-74, 78, 80, 83-86, and 88-90 are rejected under 35 U.S.C. 102(b) as being anticipated by Kingon (US 5,555,486).

Regarding claim 67, Kingon discloses (Fig 6) a method for use in the fabrication of integrated circuits (col 8 ln 20-24) comprising:

providing a substrate assembly (21; col 7 ln 24) comprising a surface, wherein the surface comprises oxygen (col 7 ln 25-26);

forming a first metal layer (29; col 7 ln 36) on at least a portion of the surface;

forming a second metal layer (30₁; col 7 ln 31-32) on at least a portion of the first metal layer;

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forming an oxidation diffusion barrier layer (31₁; gold: col 7 ln 33-34) on at least a portion of the second metal layer; and

causing oxygen to diffuse (inherent in the process: col 9 ln 6-7) through the first metal layer to oxidize one or more regions of the second metal layer.

Regarding claim 68, Kingon discloses thermally treating (col 9 ln 6-7) the substrate assembly having the first metal layer, second metal layer, and oxidation diffusion barrier layer formed thereon.

Regarding claim 69, Kingon discloses annealing the substrate assembly having the first metal layer, second metal layer, and oxidation diffusion barrier layer formed thereon at a temperature greater than 300°C (col 9 ln 6-7).

Regarding claims 71 and 72, Kingon discloses (Fig 6) the first metal layer (29) comprises platinum (col 7 ln 36).

Regarding claims 73 and 74, Kingon discloses (Fig 6) the second metal layer (30₁) comprises ruthenium (col 7 ln 32).

Regarding claim 78, Kingon discloses (Fig 6) a method for use in the fabrication of integrated circuits (col 8 ln 20-24) comprising:

providing a substrate assembly (21; col 7 ln 24) comprising a surface, wherein the surface comprises oxygen (col 7 ln 25-26);

forming a first metal layer (29; col 7 ln 36) on at least a portion of the surface, the first metal layer comprising one or more grain boundaries (unless a special process is carried out to form single-crystal platinum, the platinum layer is polycrystalline, and inherently comprises one or more grain boundaries);

forming a second metal layer (30₁; col 7 ln 31-32) on at least a portion of the first metal layer; and

forming metal oxide regions on at least portions of the first metal layer through oxidation of at least portions of the second metal layer by diffusion of oxygen through one or more grain boundaries of the first metal layer (inherent in the process: col 9 ln 6-9).

Regarding claim 80, Kingon discloses thermally treating (col 9 ln 6-7) the substrate assembly having the first metal layer, second metal layer, and oxidation diffusion barrier layer formed thereon wherein thermally treating comprises annealing the substrate assembly having the first metal layer, second metal layer, and oxidation diffusion barrier layer formed thereon at a temperature greater than 300°C (col 9 ln 6-7).

Regarding claims 83 and 84, Kingon discloses (Fig 6) the first metal layer (29) comprises platinum (col 7 ln 36).

Regarding claims 85 and 86, Kingon discloses (Fig 6) the second metal layer (30₁) comprises ruthenium (col 7 ln 32).

Regarding claim 88, Kingon discloses (Fig 6) a method for use in the fabrication of integrated circuits (col 8 ln 20-24) comprising:

providing a substrate assembly (21; col 7 ln 24) comprising a surface, wherein the surface comprises oxygen (col 7 ln 25-26);

forming a platinum layer (29; col 7 ln 36) on at least a portion of the surface;

forming a ruthenium layer (30₁; col 7 ln 31-32) on at least a portion of the platinum layer; and

forming ruthenium oxide regions on at least portions of the platinum layer through selective oxidation of the ruthenium layer by diffusion of oxygen through the platinum layer (inherent in the process: col 9 ln 6-9).

Regarding claim 89, Kingon discloses (Fig 6) forming ruthenium oxide regions on at least portions of the platinum layer through selective oxidation of the ruthenium layer comprises:

Providing an oxidation diffusion barrier layer (31₁; gold: col 7 ln 33-34) on at least a portion of the ruthenium layer;

thermally treating (col 9 ln 6-7) the substrate assembly having the platinum layer, ruthenium layer, and oxidation diffusion barrier layer formed thereon to selectively oxidize one or more regions of the ruthenium layer by diffusion of oxygen through one or more grain boundaries of the platinum layer.

Regarding claim 90, Kingon discloses thermally treating (col 9 ln 6-7) the substrate assembly having the platinum layer, ruthenium layer, and oxidation diffusion barrier layer formed thereon wherein thermally treating comprises annealing the substrate assembly having the platinum layer, ruthenium layer, and oxidation diffusion barrier layer formed thereon at a temperature greater than 300°C (col 9 ln 6-7).

Allowable Subject Matter

Claims 70, 75-77, 79, 81, 82, 87, and 91-95 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

The following is a statement of reasons for the indication of allowable subject matter: the references of record, alone or in combination, fail to disclose or suggest at least the features of:

“annealing the substrate assembly...in a non-oxidizing atmosphere”, as required by claims 70, 81, and 91;

“the oxidation diffusion barrier comprises at least one of silicon nitride, silicon oxynitride, and aluminum oxide”, as required by claims 75, 87, and 95; and

“removing the oxidation diffusion barrier and unoxidized portions of the [second] layer”, as required by claims 76, 77, 79, 82, and 92-94.

Response to Arguments

Applicant's arguments filed 04/17/2006 have been considered but are moot in view of the new ground of rejection.

Double Patenting

The nonstatutory double patenting rejection is based on a judicially created doctrine grounded in public policy (a policy reflected in the statute) so as to prevent the unjustified or improper timewise extension of the “right to exclude” granted by a patent and to prevent possible harassment by multiple assignees. A nonstatutory obviousness-type double patenting rejection is appropriate where the conflicting claims are not identical, but at least one examined application claim is not patentably distinct from the reference claim(s) because the examined application claim is either anticipated by, or would have been obvious over, the reference claim(s). See, e.g., *In re Berg*, 140 F.3d 1428, 46 USPQ2d 1226 (Fed. Cir. 1998); *In re Goodman*, 11 F.3d 1046, 29 USPQ2d 2010 (Fed. Cir. 1993); *In re Longi*, 759 F.2d 887, 225 USPQ 645 (Fed. Cir. 1985); *In re Van Ornum*, 686 F.2d 937, 214 USPQ 761 (CCPA 1982); *In re Vogel*, 422 F.2d 438, 164 USPQ 619 (CCPA 1970); and *In re Thorington*, 418 F.2d 528, 163 USPQ 644 (CCPA 1969).

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A timely filed terminal disclaimer in compliance with 37 CFR 1.321(c) or 1.321(d) may be used to overcome an actual or provisional rejection based on a nonstatutory double patenting ground provided the conflicting application or patent either is shown to be commonly owned with this application, or claims an invention made as a result of activities undertaken within the scope of a joint research agreement.

Effective January 1, 1994, a registered attorney or agent of record may sign a terminal disclaimer. A terminal disclaimer signed by the assignee must fully comply with 37 CFR 3.73(b).

Claims 67-95 are rejected on the ground of nonstatutory double patenting over claims 1-26 of U. S. Patent No. 6,534,357 since the claims, if allowed, would improperly extend the "right to exclude" already granted in the patent.

The subject matter claimed in the instant application is fully disclosed in the patent and is covered by the patent since the patent and the application are claiming common subject matter, as follows:

Claim 67 differs from patent claim 1 only in not claiming "removing".

Claim 68 claims "thermally treating" (patent claim 1).

Claim 69 claims "greater than 300°C" (patent claim 2).

Claim 70 claims "a non-oxidizing atmosphere" (patent claim 3).

Claim 71 claims a metal group (patent claim 4).

Claim 72 claims "platinum" (patent claim 5).

Claim 73 claims a metal group (patent claim 6).

Claim 74 claims "ruthenium" (patent claim 7).

Claim 75 claims a group (patent claim 8).

Claim 76 claims "removing" (patent claim 1).

Claim 77 claims etchings (patent claim 9).

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Claim 78 differs from patent claim 10 only in not expressly claiming the portions at which the metal oxide regions are formed are the "grain boundaries".

Claim 79 claims three additional steps (patent claim 11).

Claim 80 claims "greater than 300°C" (patent claim 12).

Claim 81 claims "a non-oxidizing atmosphere" (patent claim 13).

Claim 82 claims etchings (patent claim 14).

Claim 83 claims a metal group (patent claim 15).

Claim 84 claims "platinum" (patent claim 16).

Claim 85 claims a metal group (patent claim 17).

Claim 86 claims "ruthenium" (patent claim 18).

Claim 87 claims a group (patent claim 19).

Claim 88 differs from patent claim 20 in not claiming the "platinum layer having grain boundaries".

Claim 89 claims two additional steps (patent claim 21).

Claim 90 claims "greater than 300°C" (patent claim 22).

Claim 91 claims "a non-oxidizing atmosphere" (patent claim 23).

Claim 92 claims "ruthenium oxide regions" and "unoxidized ruthenium portions" (patent claim 21).

Claim 93 claims etchings (patent claim 24).

Claim 94 claims two additional steps (patent claim 26).

Claim 95 claims a group (patent claim 25).

Furthermore, there is no apparent reason why applicant was prevented from presenting claims corresponding to those of the instant application during prosecution of the application which matured into a patent. See *In re Schneller*, 397 F.2d 350, 158 USPQ 210 (CCPA 1968). See also MPEP § 804.

Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure:

Summerfelt (US 6,117,689) is relevant to the rejection of claims 67, 78, and 88 insofar as Summerfelt teaches that platinum layers allow diffusion of oxygen through the one or more grain boundaries (col 2 ln 21-21, 26, 32-34; col 4 ln 32-38, 45-47; col 5 ln 37-40) and teaches that a special deposition process is needed to form single crystal platinum (col 2 ln 49-50, 54-55; col 5 ln 48-51, 55-58; col 6 ln 49-50).

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Andrew O. Arena whose telephone number is (571) 272-5976. The examiner can normally be reached on M-F 8:30-5.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie Lee can be reached on (571) 272-1732. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

AOA
23 June 2006

A handwritten signature in black ink, appearing to read 'Eddie Lee', is positioned above the printed name and title.

EDDIE LEE
SUPERVISORY PATENT EXAMINER
TECHNOLOGY CENTER 2800